

New Jersey Semi-Conductor Products, Inc.

20 STERN AVE.
SPRINGFIELD, NEW JERSEY 07081
U.S.A.

Thyristors

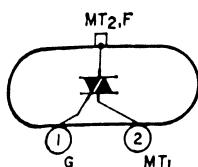
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6A, 200V

40429

6A, 400V

40430



Si gate-controlled full-wave types used for the control of ac loads in applications such as heating controls, motor controls, light dimmers, and power switching systems. JEDEC TO-66,

MAXIMUM RATINGS (For sinusoidal ac supply voltage at $f = 50/60$ Hz with resistive or inductive load)

V_{DROM}^* ($T_J = -65^\circ C$ to $100^\circ C$)	40429	40430
I_{TRMS} ($T_c = 75^\circ C$, conduction angle = 360°)	200	400
I_{TRMS} (T_A up to $100^\circ C$, conduction angle = 360°)	6	A
I_{TM} (1 cycle of principal voltage)	100	A
I_{GM} (1 μs max)	4	A
P_{GM} (1 μs max, $I_{GM} \leq 4$ A peak)	16	W
$P_{G(AV)}$	0.2	W
T_{STG}	65 to 150	W
T_c	-65 to 100	°C

See Rating Chart (Ambient Temperature)	V
100	A
4	A
16	W
0.2	W
65 to 150	W
-65 to 100	°C

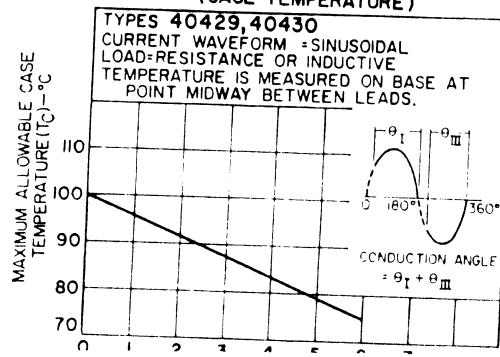
CHARACTERISTICS (At maximum electrical ratings at $T_c = 25^\circ C$)

I_{DRM}^* ($T_J = 100^\circ C$, $V_{DROM} =$ max rated value)	0.1 typ; 4 max	0.2 typ; 4 max	mA
V_{TM}^* ($i_T = 30$ A peak)	1.8 typ; 2.25	—	V
I_{IO}^* (initial principal = 150 mA dc)	15 typ; 30 max	—	mA
Commutating dv/dt^* ($V_D = V_{DROM}$, $I_{TRMS} = 6$ A, commutating $di/dt = 3.2$ A/ms, gate unenergized at $T_c = 75^\circ C$)	—	3 min; 10 typ	V/ μs
Critical dv/dt^* ($V_D = V_{DROM}$, exponential voltage rise, $T_c = 100^\circ C$)	30 min; 150 typ	20 min; 100 max	V/ μs
I_{GT}^* ($V_D = 12$ Vdc, $R_L = 12 \Omega$):	—	—	—
I ⁺ mode, V_{MT2} positive, V_G positive	15 typ; 25 max	—	mA
I ⁻ mode, V_{MT2} positive, V_G negative	25 typ; 40 max	—	mA
III ⁺ mode, V_{MT2} negative, V_G positive	25 typ; 40 max	—	mA
III ⁻ mode, V_{MT2} negative, V_G negative	15 typ; 40 max	—	mA
V_{GR}^* † ($V_D = 12$ Vdc, $R_L = 12 \Omega$)	1 typ; 2.2 max	—	V
V_{GR}^* ‡ ($V_D = V_{DROM}$, $R_L = 125 \Omega$, $T_c = 100^\circ C$)	—	0.2 min	V
t_{et} ($V_D = V_{DROM}$, $I_{GT} = 80$ mA, $t_r = 0.1 \mu s$, $i_T = 10$ A)	—	2.2	μs
θ_{J-C} (steady-state)	4 max	—	°C/W
θ_{J-A}	—	—	—

See Rating Chart (Ambient Temperature)

- * For either polarity of main terminal 2 voltage (V_{MT2}) with reference to main terminal 1.
- † For either polarity of gate voltage (V_G) with reference to main terminal 1.
- ‡ This characteristic does not apply to types 40502 and 40503.

CONDUCTION RATING CHART (CASE TEMPERATURE)



Quality Semi-Conductors